# Revised May 2002

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MM74C14 Hex Schmitt Trigger

## FAIRCHILD

SEMICONDUCTOR

## MM74C14 **Hex Schmitt Trigger**

#### **General Description**

The MM74C14 Hex Schmitt Trigger is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement transistors. The positive and negative going threshold voltages  $V_{T\scriptscriptstyle +}$  and  $V_{T\scriptscriptstyle -}$  , show low variation with respect to temperature (typ.  $0.0005 V/^{\circ}C$ at V<sub>CC</sub> = 10V), and hysteresis,  $V_{T+} - V_{T-} \ge 0.2 V_{CC}$  is guaranteed.

All inputs are protected from damage due to static discharge by diode clamps to  $\rm V_{CC}$  and GND.

#### **Features**

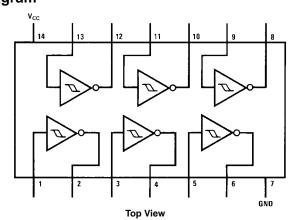
■ Wide supply voltage range: 3.0V to 15V

- High noise immunity: 0.70 V<sub>CC</sub> (typ.)
- Low power: TTL compatibility:
- 0.4  $V_{CC}$  (typ.)  $\,$  0.2  $V_{CC}$  guaranteed
- Hysteresis: 0.4 V<sub>CC</sub> (typ.): 0.2 V<sub>CC</sub> guaranteed

## **Ordering Code:**

Order Number	Package Number	Package Description			
MM74C14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow			
MM74C14N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.					

## **Connection Diagram**



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## Absolute Maximum Ratings(Note 1)

Voltage at Any Pin	-0.3Vto V <sub>CC</sub> + 0.3V
Operating Temperature Range	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Power Dissipation	
Dual-In-Line	700 mW
Small Outline	500mW
Operating V <sub>CC</sub> Range	3.0V to 15V
Absolute Maximum V <sub>CC</sub>	18V
Lead Temperature	
(Soldering, 10 seconds)	260°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions for actual device operation.

### **DC Electrical Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS TO C	MOS		4			
V <sub>T+</sub> Positi	Positive Going Threshold Voltage	$V_{CC} = 5V$	3.0	3.6	4.3	Т
		$V_{CC} = 10V$	6.0	6.8	8.6	v
		$V_{CC} = 15V$	9.0	10.0	12.9	1
/ <sub>T-</sub>	Negative Going Threshold Voltage	$V_{CC} = 5V$	0.7	1.4	2.0	
		$V_{CC} = 10V$	1.4	3.2	4.0	V
		V <sub>CC</sub> = 15V	2.1	5.0	6.0	1
V <sub>T+</sub> – V <sub>T-</sub>	Hysteresis	$V_{CC} = 5V$	1.0	2.2	3.6	
		$V_{CC} = 10V$	2.0	3.6	7.2	V
		$V_{CC} = 15V$	3.0	5.0	10.8	1
V <sub>OUT(1)</sub>	Logical "1" Output Voltage	$V_{CC} = 5V, I_{O} = -10 \ \mu A$	4.5			v
		$V_{CC} = 10V, I_{O} = -10 \ \mu A$	9.0			v
VOUT(0)	Logical "0" Output Voltage	$V_{CC} = 5V, I_{O} = 10 \ \mu A$			0.5	v
		$V_{CC} = 10V, I_{O} = 10 \ \mu A$			1.0	v
IN(1)	Logical "1" Input Current	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 15V		0.005	1.0	μA
IN(0)	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1.0	-0.005		μA
CC	Supply Current	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 0V/15V		0.05	15	
		V <sub>CC</sub> = 5V, V <sub>IN</sub> = 2.5V (Note 2)		20		<u>ا</u>
		V <sub>CC</sub> = 10V, V <sub>IN</sub> = 5V (Note 2)		200		μA
		V <sub>CC</sub> = 15V, V <sub>IN</sub> = 7.5V (Note 2)		600		1
CMOS/LPT1	L INTERFACE		1	1		
VIN(1)	Logical "1" Input Voltage	$V_{CC} = 5V$	4.3			V
VIN(0)	Logical "0" Input Voltage	$V_{CC} = 5V$			0.7	V
VOUT(1)	Logical "1" Output Voltage	74C, $V_{CC} = 4.75V$ , $I_{O} = -360 \ \mu A$	2.4			V
VOUT(0)	Logical "0" Output Voltage	74C, $V_{CC} = 4.75V$ , $I_O = 360 \ \mu A$			0.4	V
	RIVE (see Family Characteristics Data	Sheet) T <sub>A</sub> = 25°C (Short Circuit Current	)	11		
SOURCE	Output Source Current	$V_{CC} = 5V, V_{OUT} = 0V$	-1.75	-3.3		mA
0001102	(P-Channel)					
ISOURCE	Output Source Current	$V_{CC} = 10V, V_{OUT} = 0V$	-8.0	-15		mA
	(P-Channel)					
I <sub>SINK</sub>	Output Sink Current	$V_{CC} = 5V, V_{OUT} = V_{CC}$	1.75	3.6		mA
	(N-Channel)					
I <sub>SINK</sub>	Output Sink Current	$V_{CC} = 10V, V_{OUT} = V_{CC}$	8.0	16		mA
	(N-Channel)					
	$v$ one of the six inputs is at $\frac{1}{2}$ V <sub>CC</sub> ; the others			1		L

## AC Electrical Characteristics (Note 3)

$T_A = 25^{\circ}C$ , $C_L = 50$ pF, unless otherwise specified								
Symbol	Parameter	Conditions	Min	Тур	Max	Units		
t <sub>PD0</sub>	Propagation Delay	$V_{CC} = 5V$		220	400	n		
t <sub>PD1</sub>	from Input to Output	$V_{CC} = 10V$		80	200	ns		
C <sub>IN</sub>	Input Capacitance	Any Input (Note 4)		5.0		pF		
C <sub>PD</sub>	Power Dissipation Capacitance	Per Gate (Note 5)		20		pF		

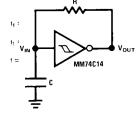
Note 3: AC Parameters are guaranteed by DC correlated testing.

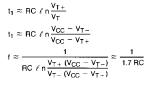
Note 4: Capacitance is guaranteed by periodic testing.

Note 5: C<sub>PD</sub> determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics Application Note—AN-90.

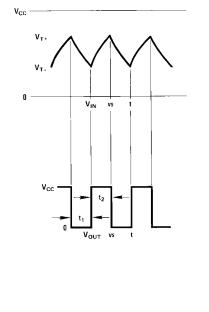
#### **Typical Applications**





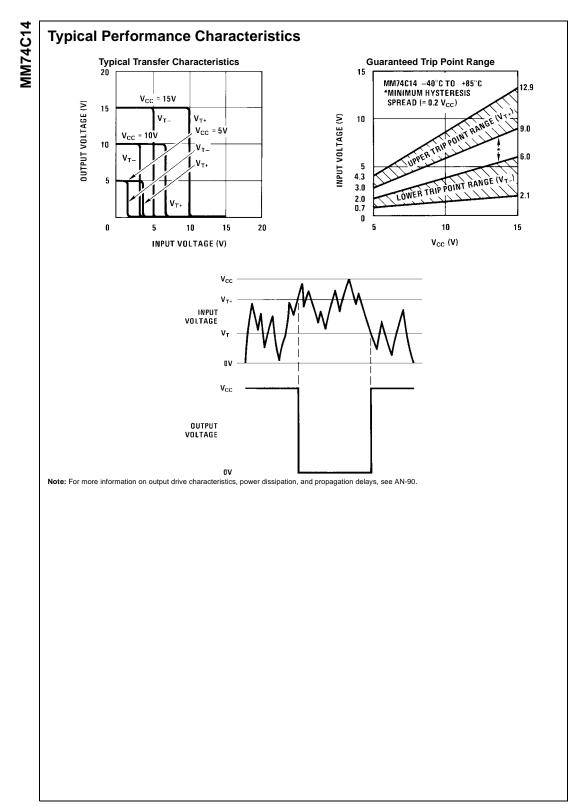


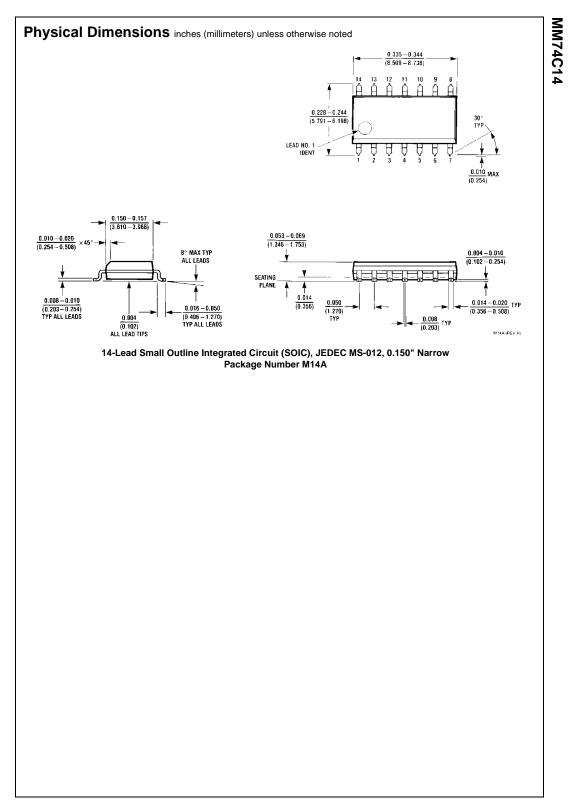
Note: The equations assume  $t_1 + t_2 \gg t_{pd0} + t_{pd1}$ 

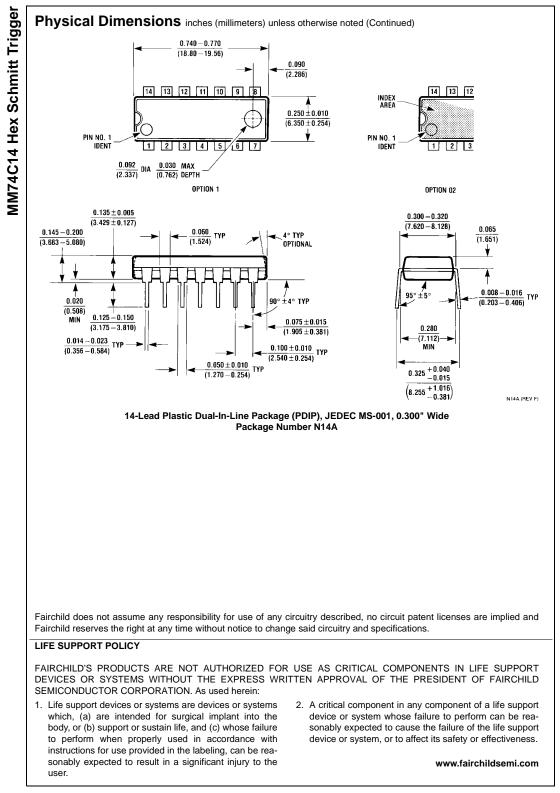


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